

Afisarea articolelor 1-7(7) pentru cuvântul-cheie "Photoelectricity"

Spatially resolved cathodoluminescence of GaN nanostructures fabricated by photoelectrochemical etching

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Electrical and photoelectrical properties of glassy As₂Se₃ doped with Mn, Dy and Sm

Iovu Mihail, Andrieş Andrei, Shutov Serghei, Bulgaru M., Popescu Mihai A., Sava Florinel, Lorinczi Adam

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Design of trapped surface charge for the photoelectrochemical fabrication of GaN mesostructures

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Photoelectric properties of ZnTe-CdSe and CdSe-ZnTe thin films heterojunctions

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Atomic structure and electron transport properties of glassy As₂Se₃:Snx

Andrieş Andrei, Popescu Mihai A., Iovu Mihail, Verlan Victor, Shutov Serghei, Bulgaru M., Colomeico Eduard, Malcov S., Leonovici Minola Rodica, Mihai V., Şteflea Mioara, Zamfira Sorin Constantin

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Investigation of some photoelectric and luminescence properties of gamma La₂S₃ single crystals

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Photoelectrochemical solar cells on the base of multinary layered semiconductors

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